

Device Modeling Report

COMPONENTS: Power MOSFET (Professional)
PART NUMBER: SSM3K116TU
MANUFACTURER: TOSHIBA
Body Diode (Professional) / ESD Protection Diode

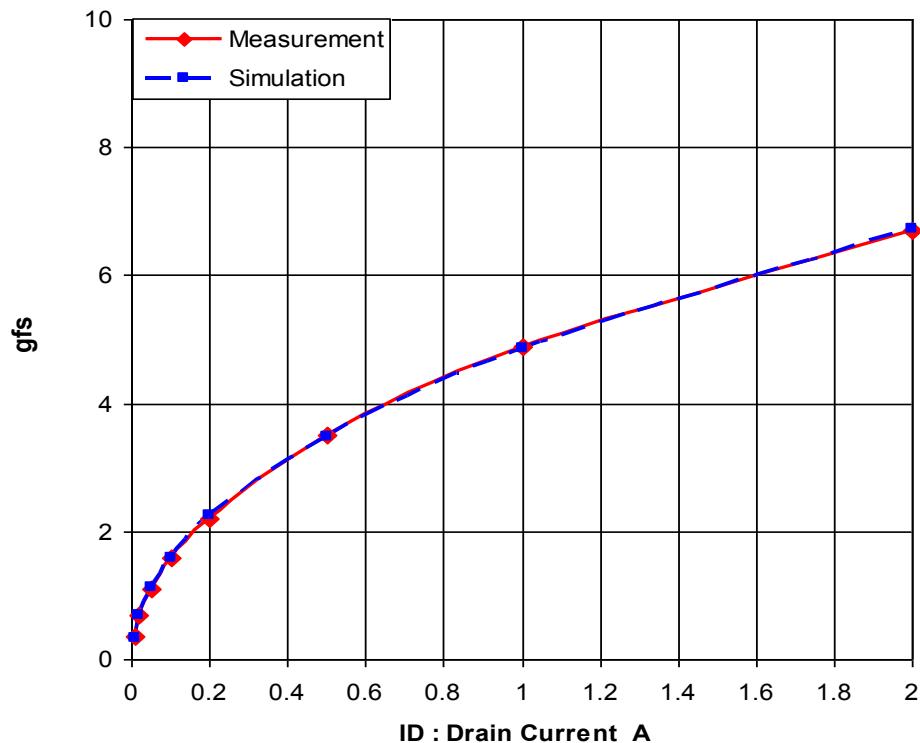


MOSFET MODEL

Pspice model parameter	Model description
LEVEL	
L	Channel Length
W	Channel Width
KP	Transconductance
RS	Source Ohmic Resistance
RD	Ohmic Drain Resistance
VTO	Zero-bias Threshold Voltage
RDS	Drain-Source Shunt Resistance
TOX	Gate Oxide Thickness
CGSO	Zero-bias Gate-Source Capacitance
CGDO	Zero-bias Gate-Drain Capacitance
CBD	Zero-bias Bulk-Drain Junction Capacitance
MJ	Bulk Junction Grading Coefficient
PB	Bulk Junction Potential
FC	Bulk Junction Forward-bias Capacitance Coefficient
RG	Gate Ohmic Resistance
IS	Bulk Junction Saturation Current
N	Bulk Junction Emission Coefficient
RB	Bulk Series Resistance
PHI	Surface Inversion Potential
GAMMA	Body-effect Parameter
DELTA	Width effect on Threshold Voltage
ETA	Static Feedback on Threshold Voltage
THETA	Modility Modulation
KAPPA	Saturation Field Factor
VMAX	Maximum Drift Velocity of Carriers
XJ	Metallurgical Junction Depth
UO	Surface Mobility

Transconductance Characteristic

Circuit Simulation Result

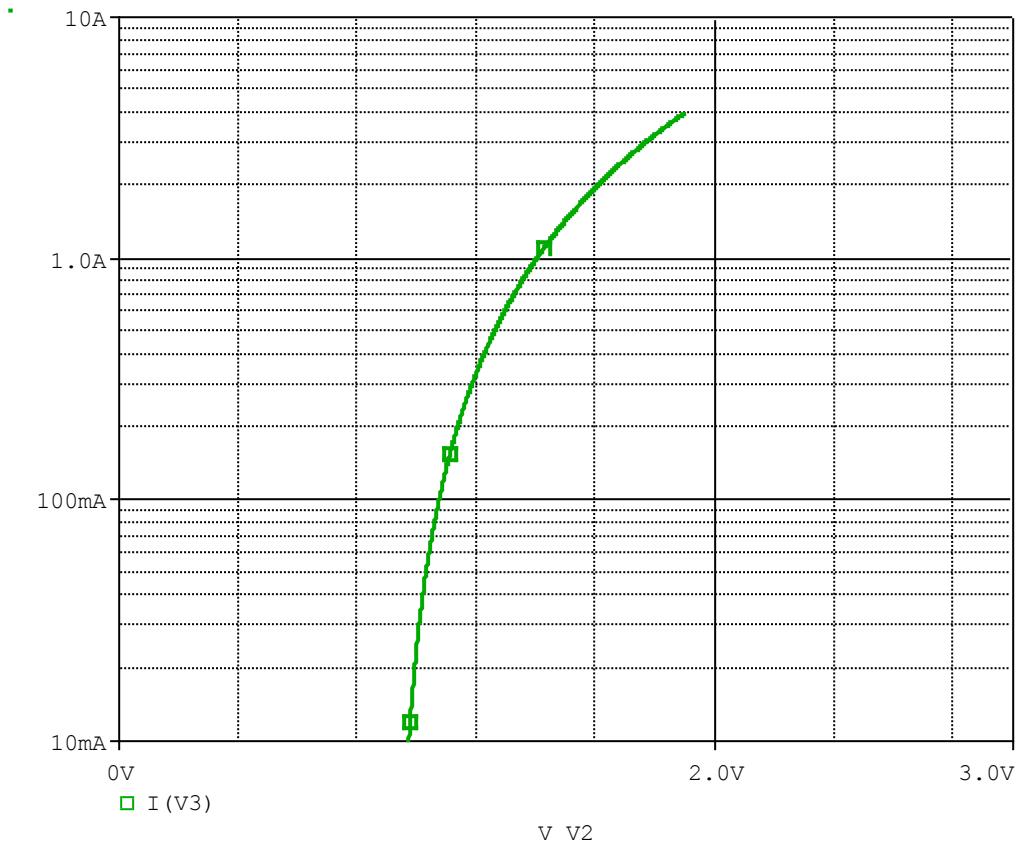


Comparison table

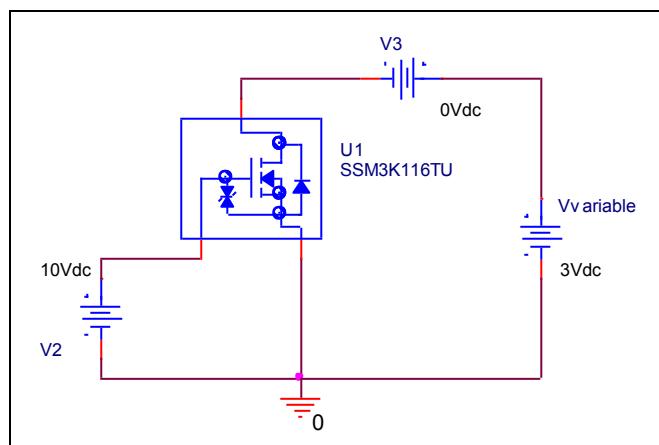
Id(A)	gfs		Error(%)
	Measurement	Simulation	
0.010	0.350	0.340	-2.857
0.020	0.700	0.686	-2.000
0.050	1.100	1.130	2.727
0.100	1.580	1.598	1.139
0.200	2.200	2.240	1.818
0.500	3.500	3.480	-0.571
1.000	4.880	4.850	-0.615
2.000	6.700	6.730	0.448

V_{gs}-I_d Characteristic

Circuit Simulation result

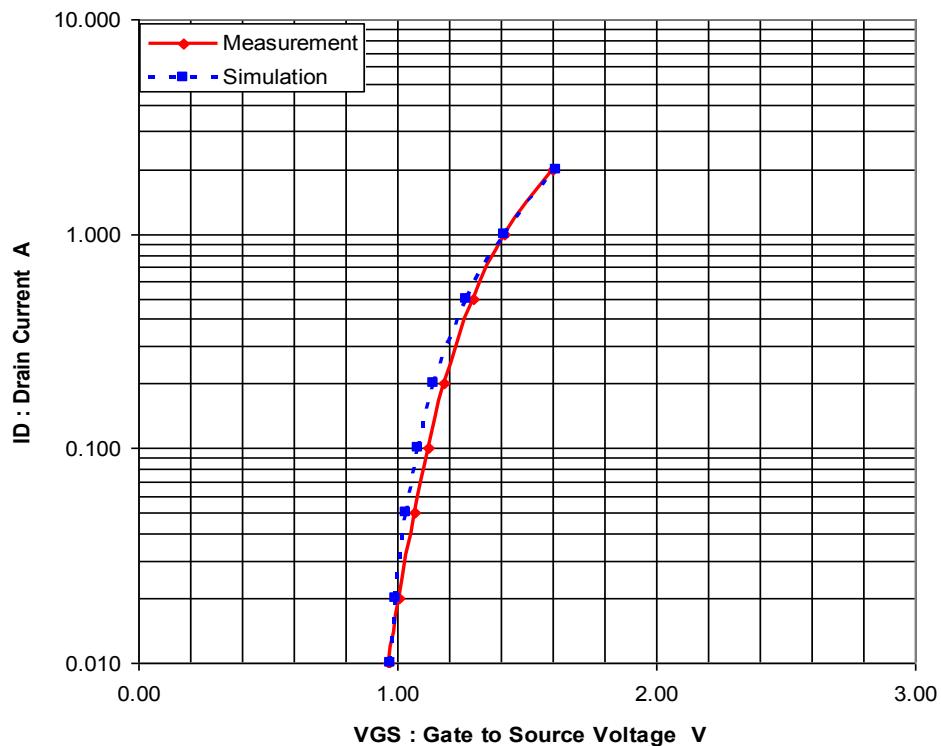


Evaluation circuit



Comparison Graph

Circuit Simulation Result

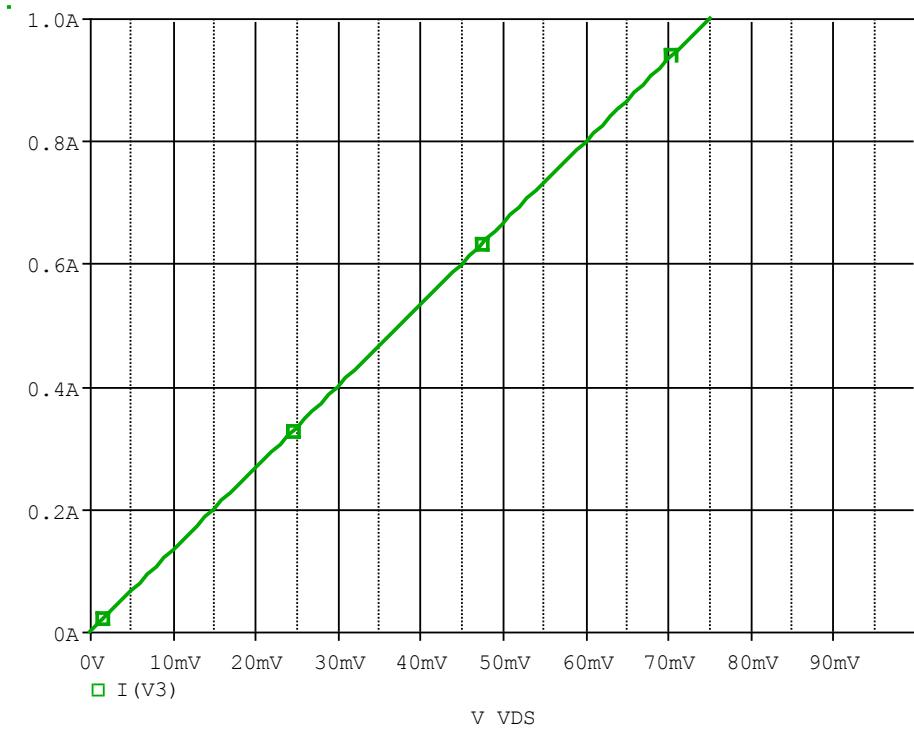


Simulation Result

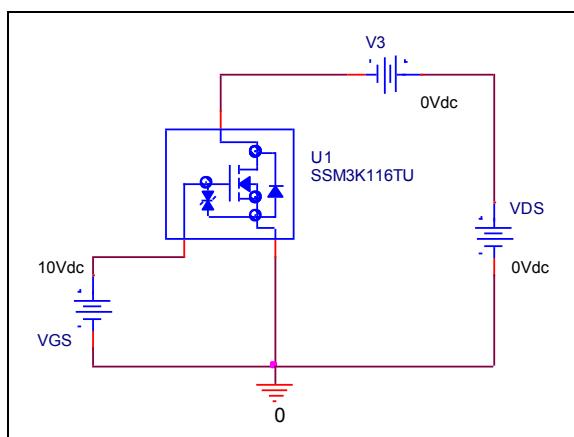
I_D (A)	V_{GS} (V)		Error (%)
	Measurement	Simulation	
0.010	0.968	0.976	0.826
0.020	1.008	0.995	-1.290
0.050	1.066	1.034	-3.002
0.100	1.120	1.078	-3.750
0.200	1.180	1.138	-3.559
0.500	1.290	1.267	-1.783
1.000	1.415	1.410	-0.353
2.000	1.600	1.612	0.750

Rds(on) Characteristic

Circuit Simulation result



Evaluation circuit

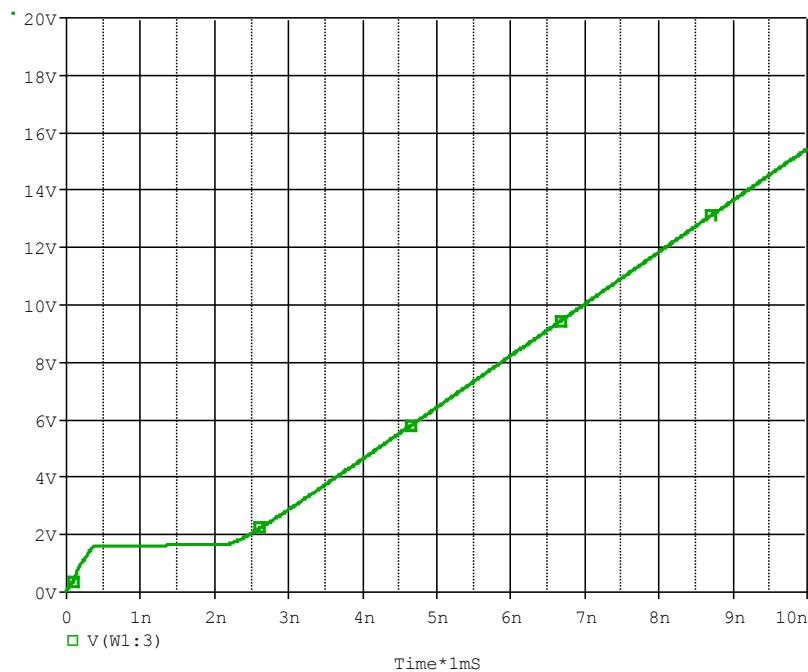


Simulation Result

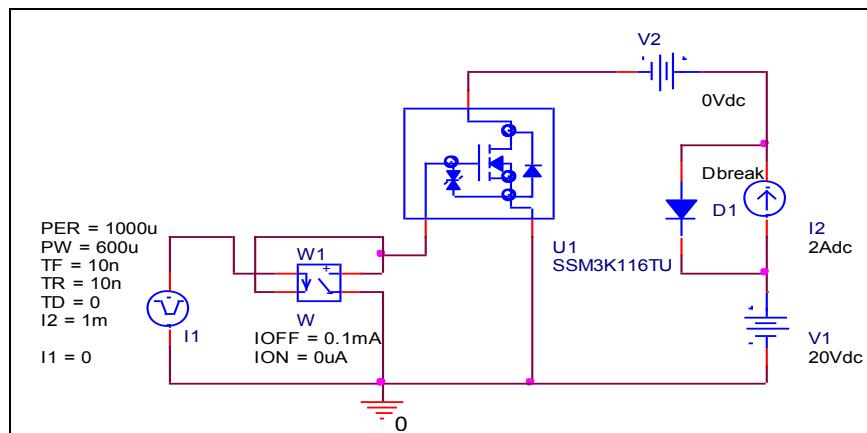
I _D =0.5A, V _{GS} =4.5V	Measurement	Simulation	Error (%)
R _{DS} (on) (Ω)	75.000	75.095	0.127

Gate Charge Characteristic

Circuit Simulation result



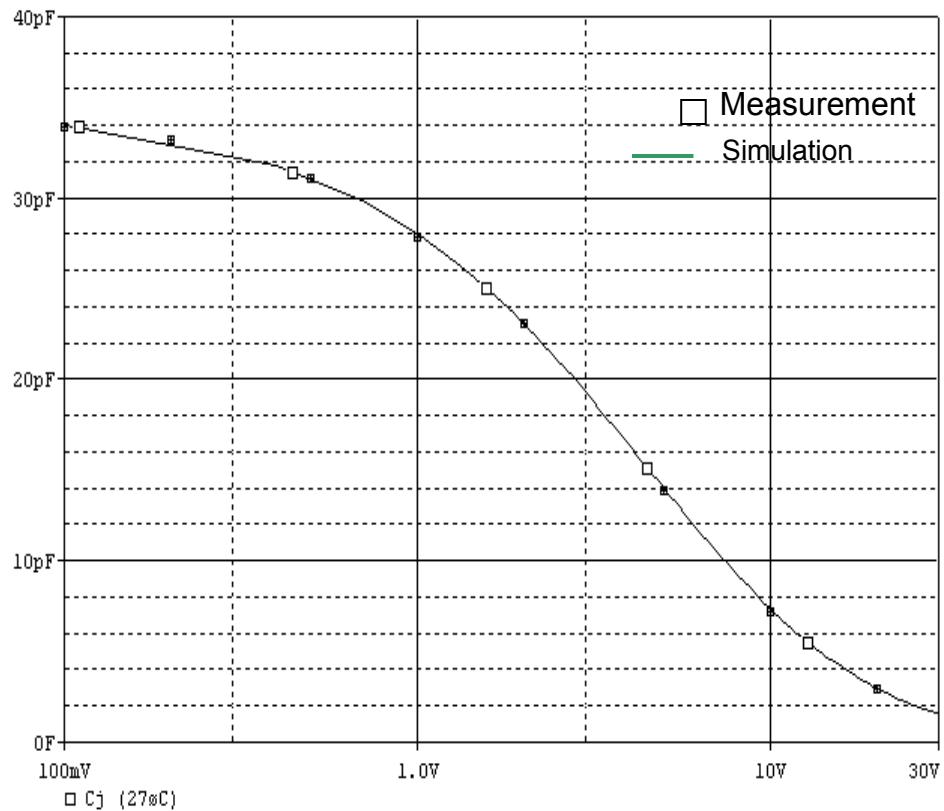
Evaluation circuit



Simulation Result

$V_{DD}=20V, I_D=2A$, $V_{GS}=10V$	Measurement	Simulation	Error (%)
Qgs(nc)	0.400	0.401	0.250
Qgd(nc)	1.800	1.807	0.389
Qg(nc)	7.000	7.009	0.129

Capacitance Characteristic

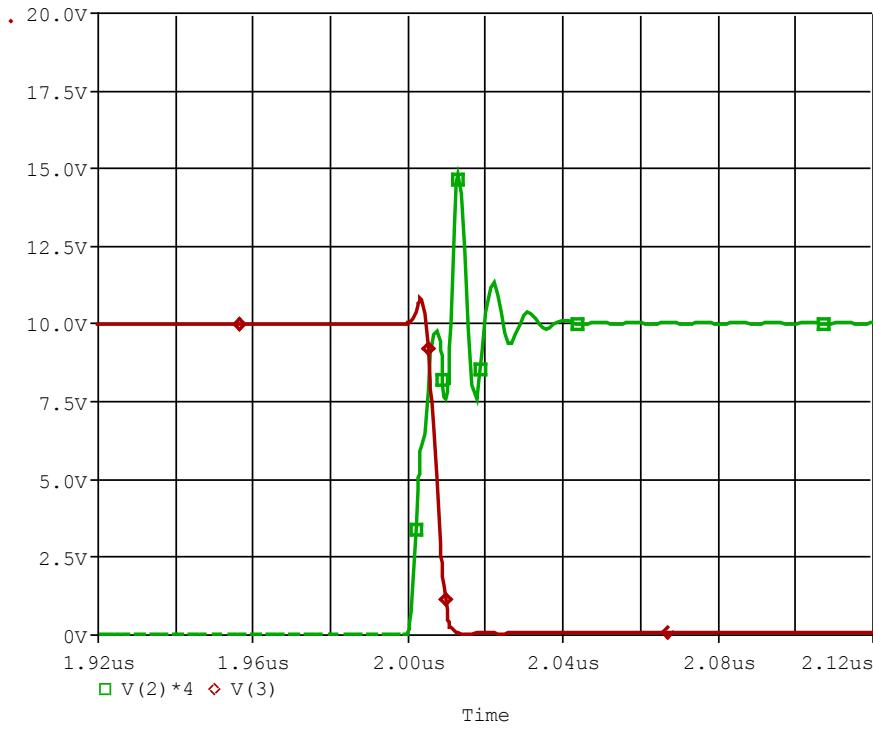


Simulation Result

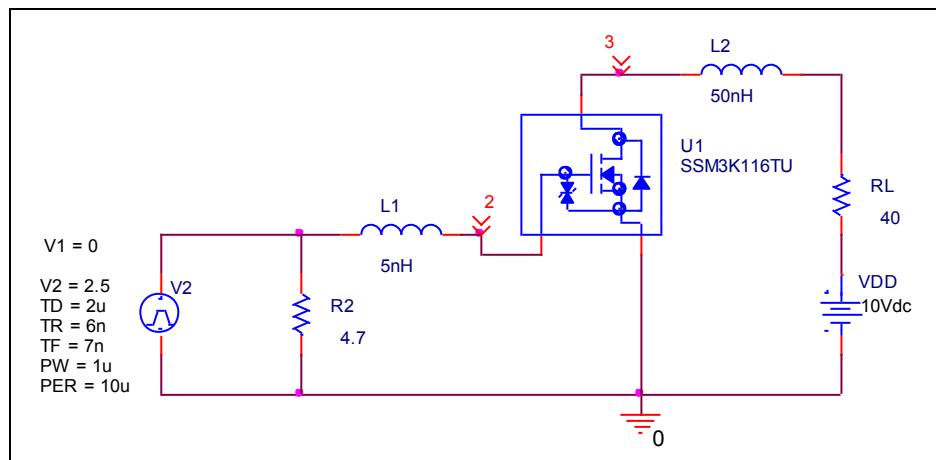
V _{DS} (V)	C _{bd} (pF)		Error(%)
	Measurement	Simulation	
0.100	34.000	34.005	0.015
0.200	33.300	33.250	-0.150
0.500	31.200	31.160	-0.128
1.000	27.900	28.060	0.573
2.000	23.200	23.080	-0.517
5.000	14.000	13.995	-0.036
10.000	7.300	7.350	0.685
20.000	3.000	2.998	-0.067

Switching Time Characteristic

Circuit Simulation result



Evaluation circuit

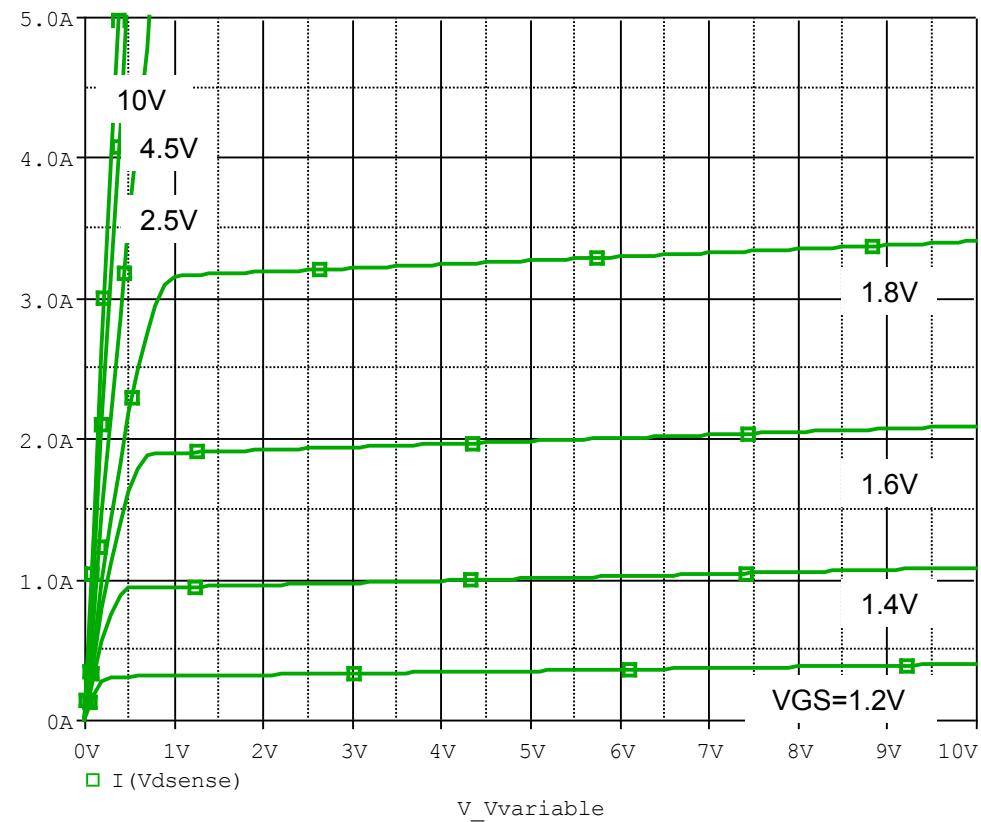


Simulation Result

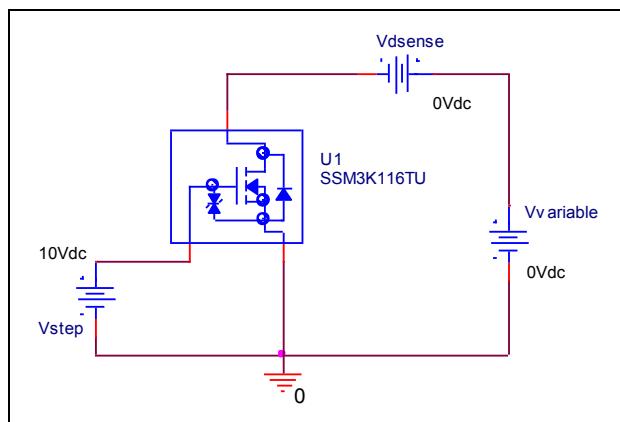
$I_D=0.25A, V_{DD}=10V$ $V_{GS}=2.5V$	Measurement	Simulation	Error(%)
Ton(ns)	9.000	8.997	-0.033

Output Characteristic

Circuit Simulation result

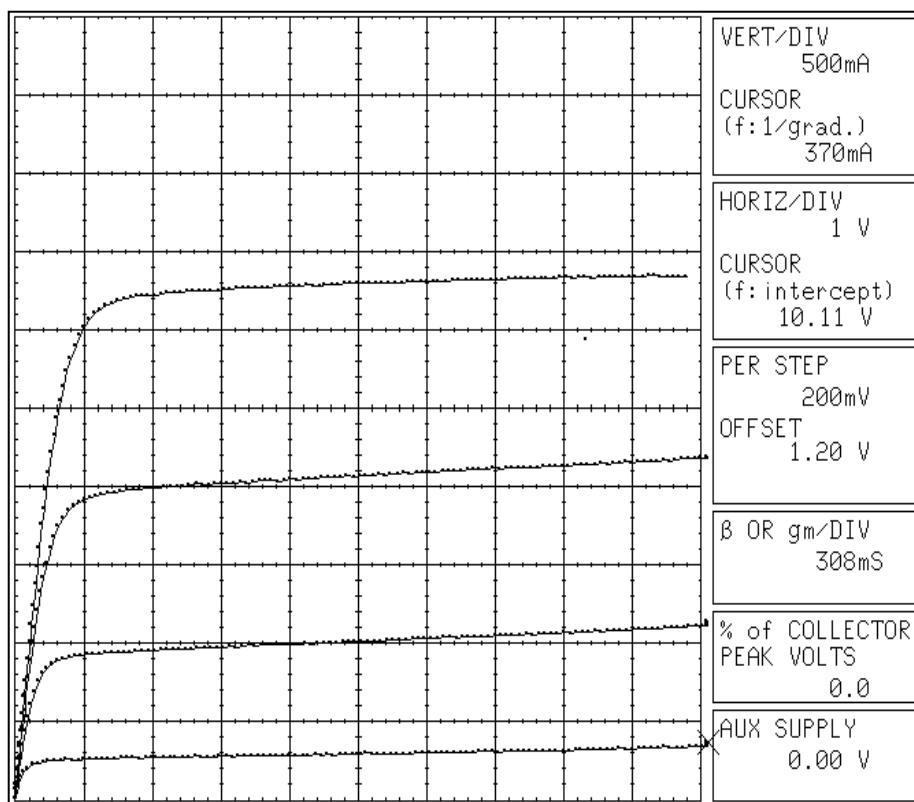


Evaluation circuit



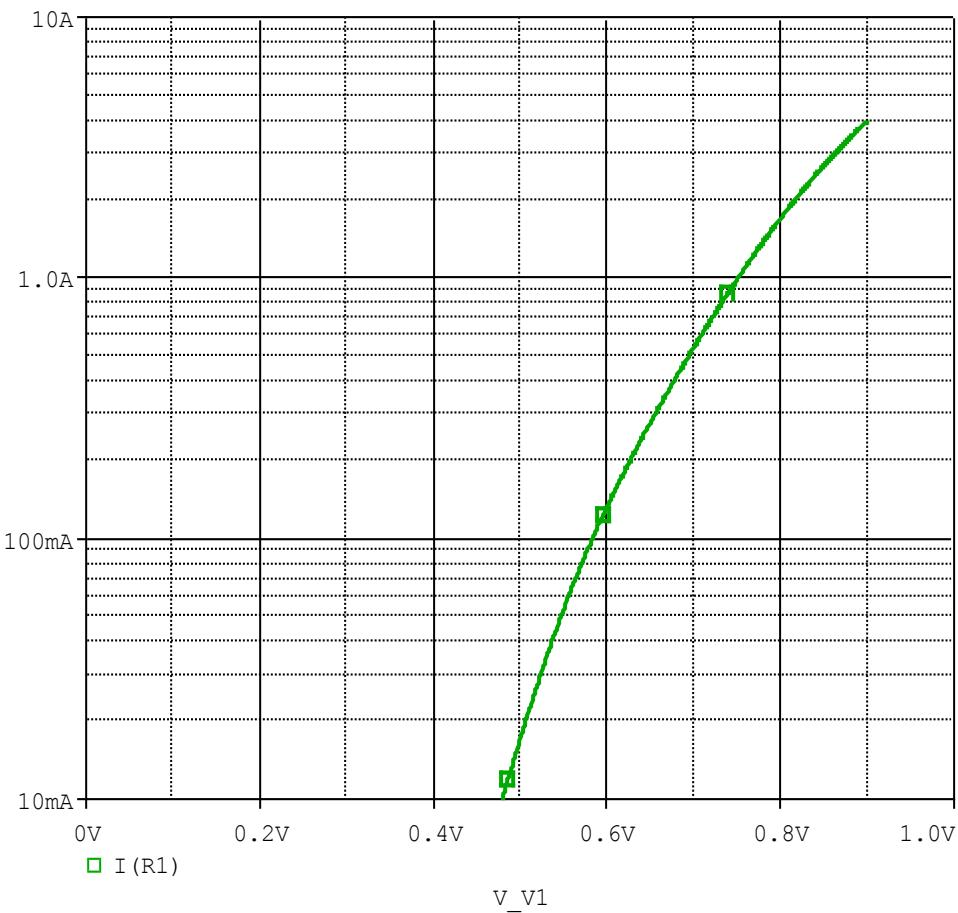
Output Characteristic

Reference

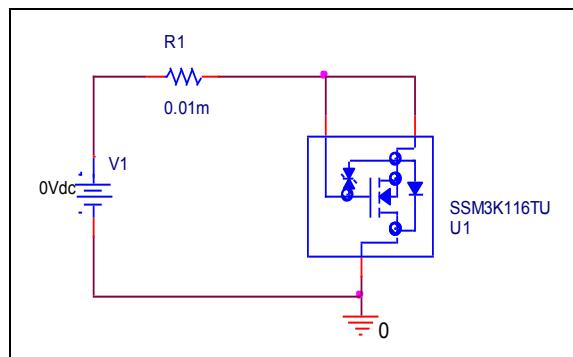


Forward Current Characteristic

Circuit Simulation Result

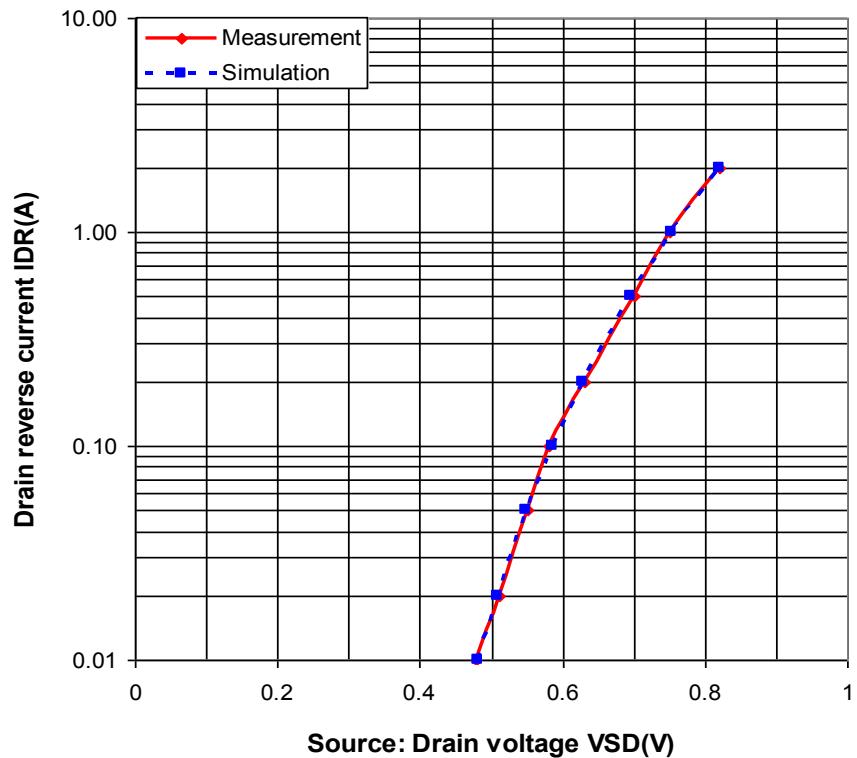


Evaluation Circuit



Comparison Graph

Circuit Simulation Result

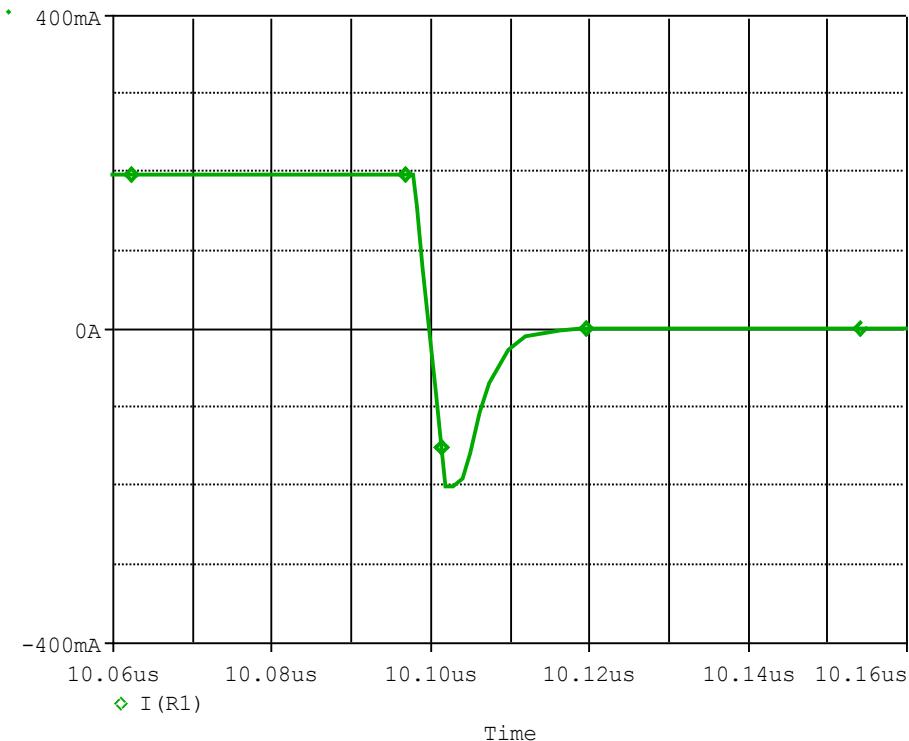


Simulation Result

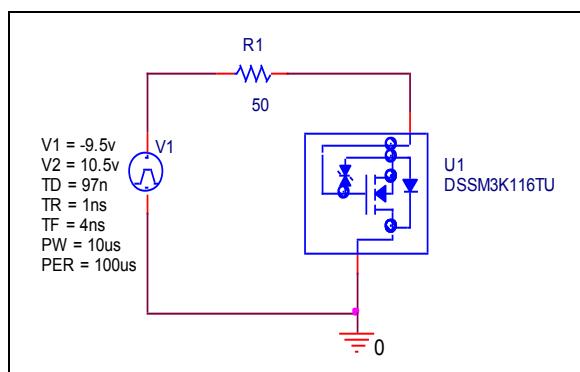
IDR(A)	VDS(V) Measurement	VDS(V) Simulation	%Error
0.010	0.480	0.481	0.208
0.020	0.510	0.509	-0.196
0.050	0.550	0.549	-0.182
0.100	0.580	0.585	0.862
0.200	0.630	0.629	-0.159
0.500	0.700	0.695	-0.714
1.000	0.750	0.754	0.533
2.000	0.820	0.821	0.122

Reverse Recovery Characteristic

Circuit Simulation Result



Evaluation Circuit

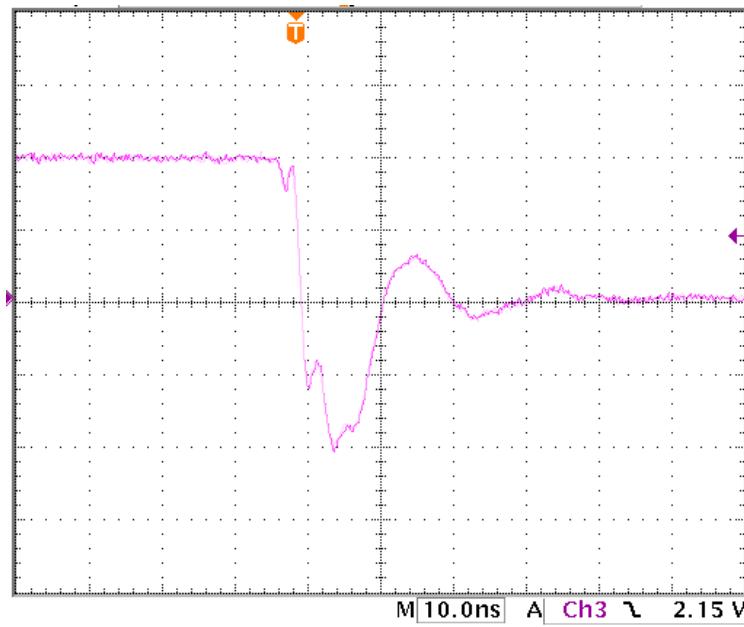


Compare Measurement vs. Simulation

	Measurement	Simulation	Error (%)
Trj(ns)	4.200	4.227	0.643
trb(ns)	6.400	6.370	-0.477
trr(ns)	10.600	10.597	-0.028

Reverse Recovery Characteristic

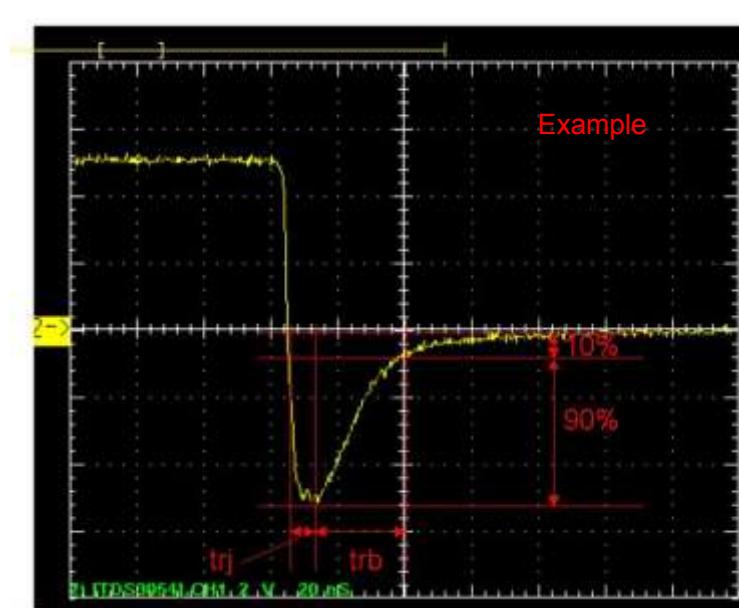
Reference



Trj=4.2(ns)

Trb=6.4(ns)

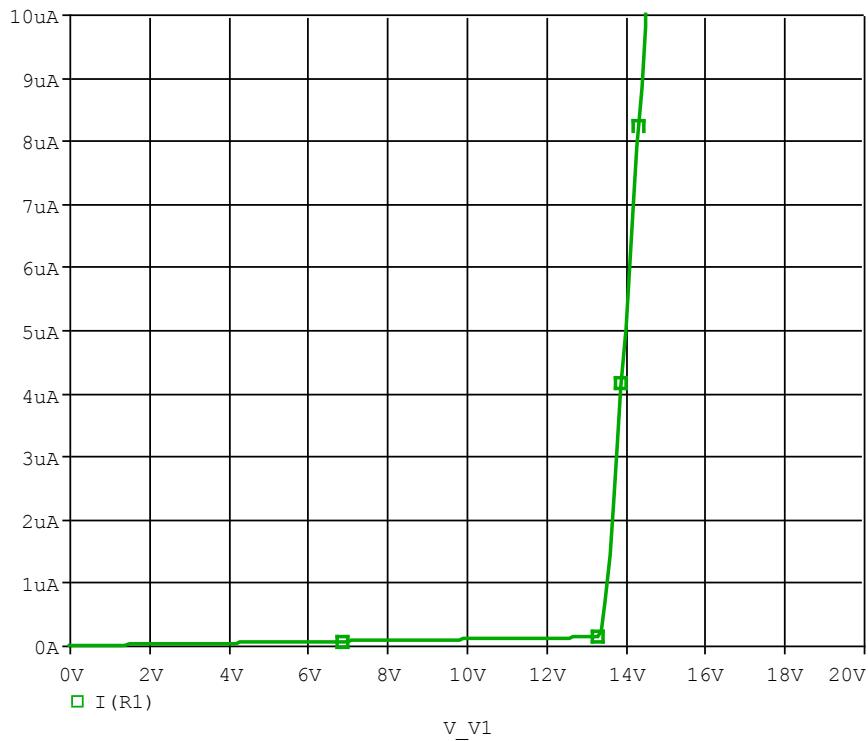
Conditions: Ifwd=Irev=0.2(A), RI=50



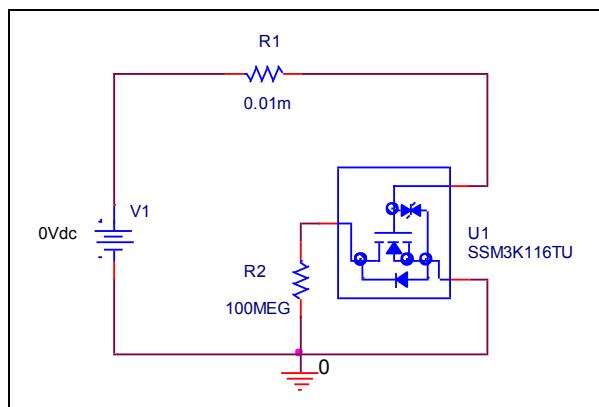
Relation between trj and trb

Zener Voltage Characteristic

Circuit Simulation Result



Evaluation Circuit



Zener Voltage Characteristic

Reference

